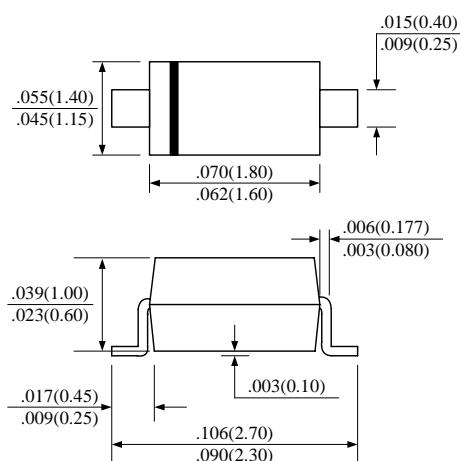


Schottky Rectifier - 0.5Amp 30Volt

Features

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- For use in low voltage high frequency inverters, free wheeling and polarity protection application
- High temperature soldering guaranteed
- High reliability
- High surge current capability
- Epitaxial construction
- Lead free device
- ESD sensitive product handling required

SOD-323



Mechanical data

- Case : Molded plastic
- Epoxy : UL 94V-0 rate flame retardant
- Terminals : Solder plated, solderable per MIL-STD-750,method 2026
- Polarity : Color band denotes cathode end

Maximum ratings and Electrical characteristics

| TYPE | SYMBOL | CH520S-30PT | UNIT |
|---|------------------|-----------------|------|
| Maximum Recurrent Peak Reverse Voltage | V _{RRM} | 30 | V |
| Maximum RMS Voltage | V _{RMS} | 21 | V |
| Maximum DC Blocking Voltage | V _{DC} | 20 | V |
| Maximum Average Forward Rectified Current | I _o | 0.5 | A |
| Peak Forward urge Current, 8.3ms single half sine-wave | I _{FSM} | 2.0 | A |
| Maximum Instantaneous Forward Voltage | V _F | IF = 100mA 0.36 | V |
| | | IF = 500mA 0.47 | |
| Maximum Average Reverse Current at V _R = 20V | I _R | 100 | µA |
| Typical Junction Capacitance between Terminal (Note 1) | C _J | 15.0 | pF |
| Operating Temperature Range | T _J | 125 | °C |
| Storage Temperature Range | T _{STG} | -40 - 125 | °C |

Note: Measured at 1.0 MHz and applied reverse voltage of 10.0 volts

August 2007 / Rev.5

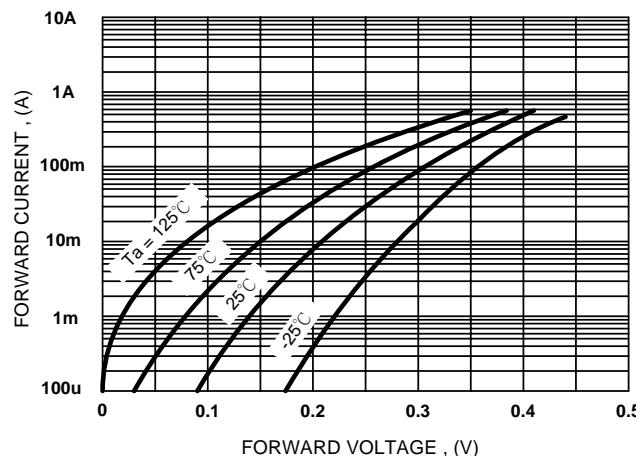


Figure 1. Forward Characteristics

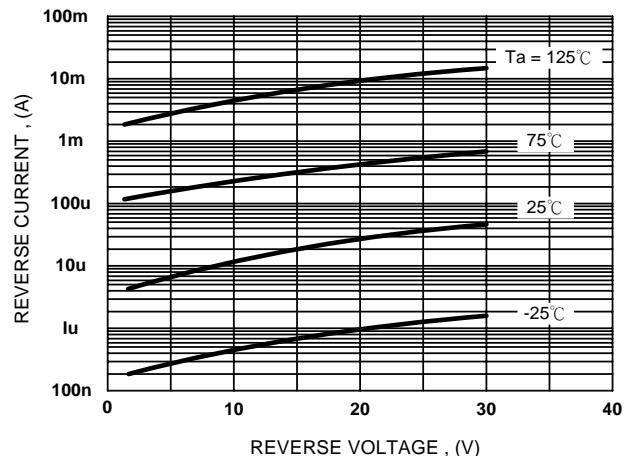


Figure 2. Reverse Characteristics

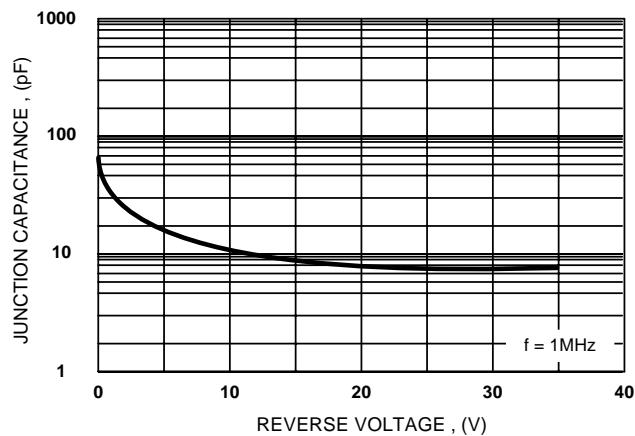


Figure 3. Typical Junction Capacitance

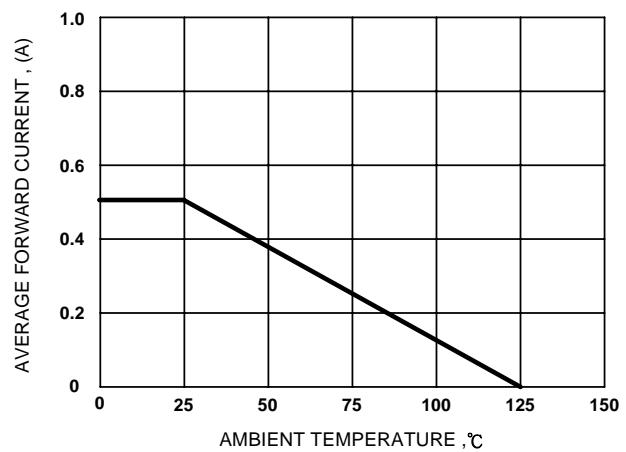


Figure 4. Forward Current Derating Curve